

1-Line , Bi-directional , Transient Voltage Suppressor

Description

PESDU0511P0 is a bi-directional TVS (Transient Voltage Suppressor). It has been specifically designed to protect sensitive electronic components which are connected to low speed data lines and control lines from over-stress caused by ESD (Electrostatic Discharge) and Lightning . PESDU0511P0 may be used to provide ESD protection up to ±30KV (air and contact discharge) according to IEC61000-4-2, and withstand peak pulse current up to 7A(8/20µs) according to IEC61000-4-5 . PESDU0511P0 is available in DFN0603-2 package. Standard products are Pb-free and Halogen-free.

Features

- Operating voltage: 5V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: ±30kV
 - Contact discharge: ±30kV
 - IEC61000-4-5 (Lightning) 7A (8/20µs)
- RoHS Compliant

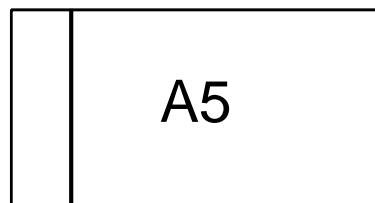
Mechanical Characteristics

- Package: DFN0603-2 (0.6x0.3x0.3mm)
- Case Material: “Green” Molding Compound.
- Moisture Sensitivity: Level 1 per J-STD-020
- Marking Information: See Below

Applications

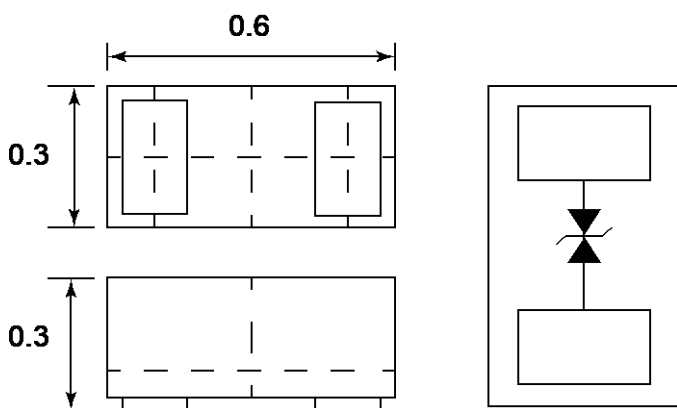
- Cellular Handsets
- USB V_{BUS} and CC Line Protection
- Microphone Line Protection
- GPIO Protection

Marking Information



A5 = Device Marking Code

Dimensions and Pin Configuration



Package Dimensions

Circuit and Pin Schematic

Ordering Information

Part Number	Shipping	Reel Size
PESDU0511P0	10000/Tape & Reel	7 inch

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	P _{PK}	84	W
Peak Pulse Current (8/20µs)	I _{PP}	7.0	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	±30 ±30	kV
Lead temperature	T _L	260	°C
Operating Temperature Range	T _{OP}	-40 ~ +85	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

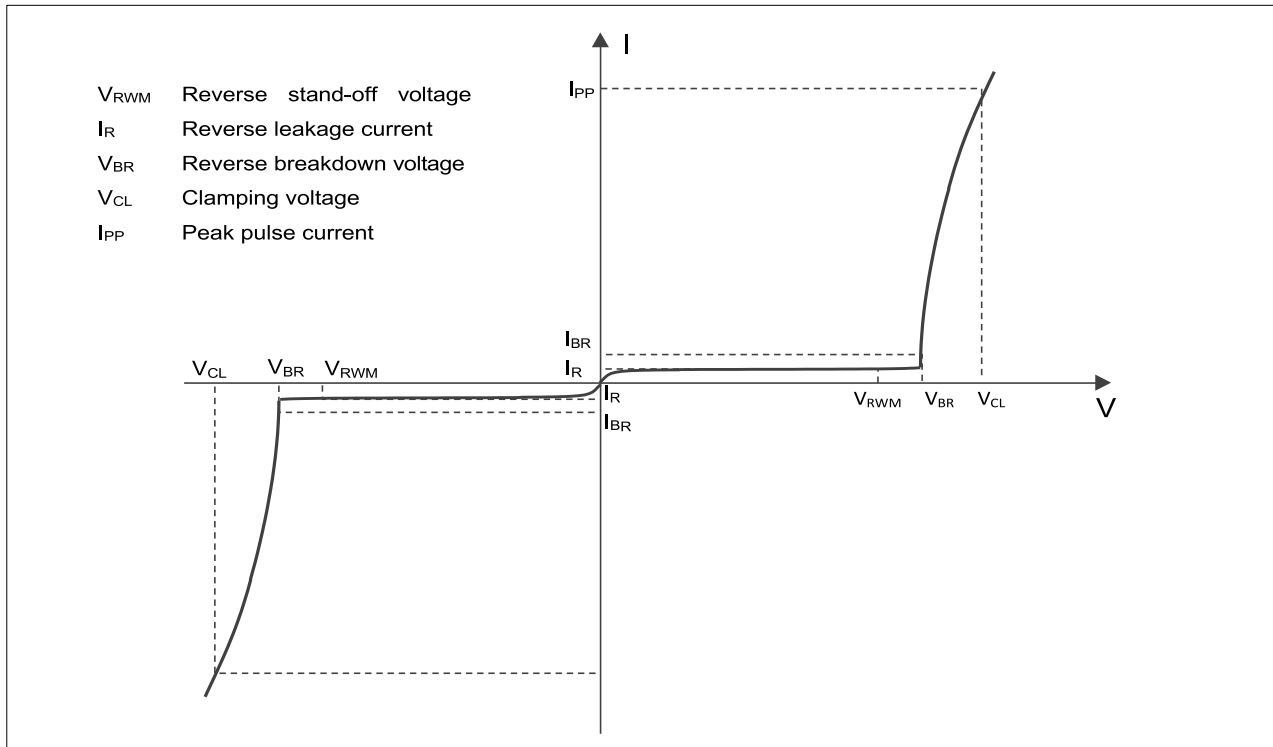
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			5	V	
Breakdown Voltage	V _{BR}	5.3			V	I _T = 1mA
Reverse Leakage Current	I _R			0.1	µA	V _{RWM} =5V
Clamping voltage ¹⁾	V _{CL}		9.0		V	I _{PP} = 16A, t _p = 100ns
Dynamic resistance ¹⁾	R _{DYN}		0.2		Ω	
Clamping voltage ²⁾	V _{CL}		9.0		V	V _{ESD} = 8kV
Clamping Voltage ³⁾	V _C			8	V	I _{PP} = 1A(8/20µs pulse)
Clamping Voltage ³⁾	V _C			12	V	I _{PP} = 7A(8/20µs pulse)
Junction Capacitance	C _J		16	20	pF	V _R = 0V, f = 1MHz

Notes:

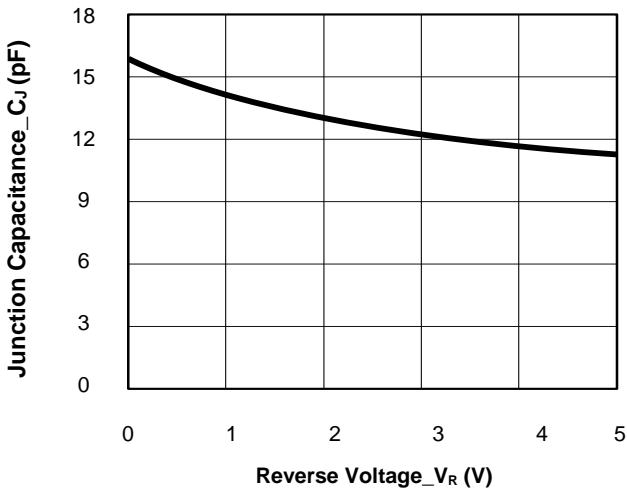
- 1) TLP parameter: Z₀ = 50Ω, t_p = 100ns, t_r = 2ns, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A.
- 2) Contact discharge mode, according to IEC61000-4-2.
- 3) Non-repetitive current pulse, according to IEC61000-4-5.

Electrical characteristics ($T_A = 25^\circ\text{C}$, unless otherwise noted)

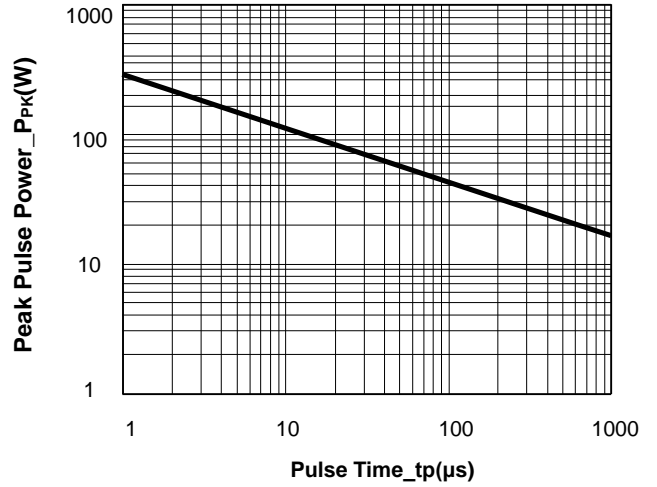


Definitions of electrical characteristics

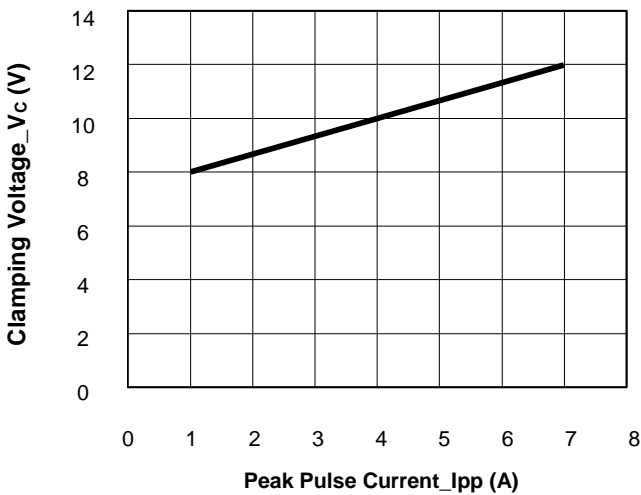
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



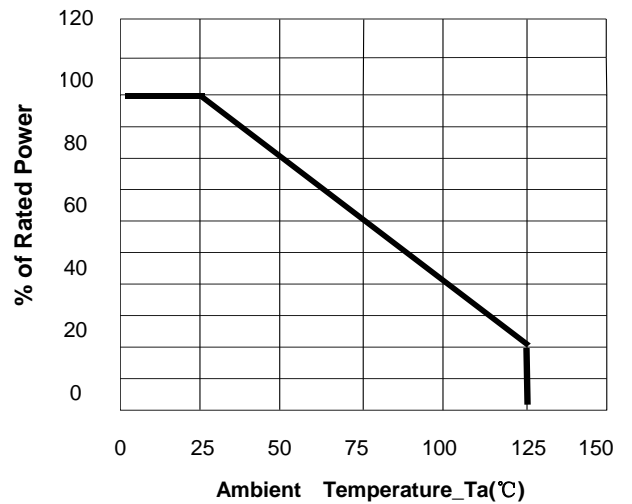
Junction Capacitance vs. Reverse Voltage



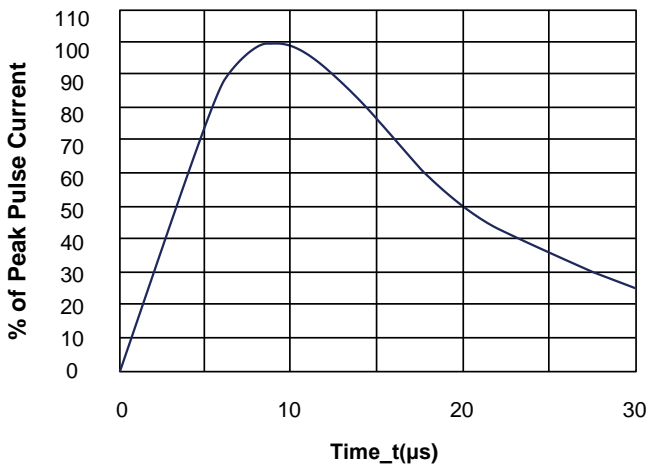
Peak Pulse Power vs. Pulse Time



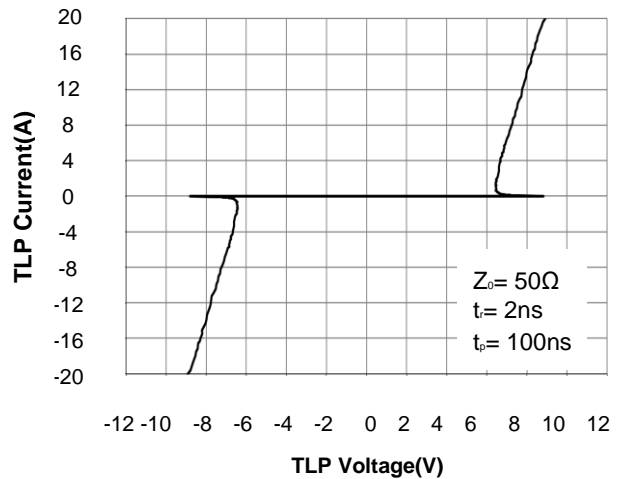
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve

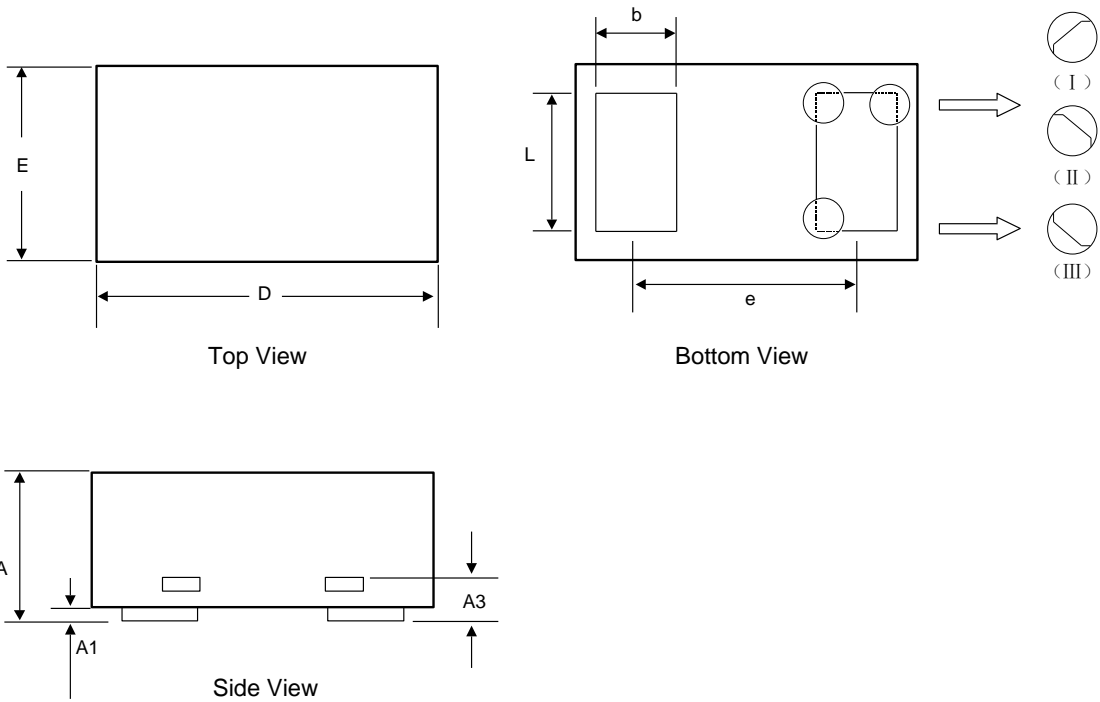


8/20μs Pulse Waveform



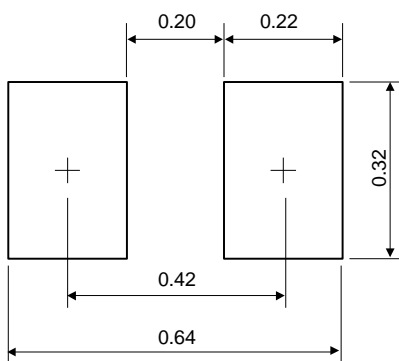
TLP Measurement

DFN0603-2 Package Outline Drawing



Symbol	Dimensions in Millimeters		
	Min.	Typ.	Max.
A	0.230	0.300	0.350
A1	0.000	-	0.050
A3	0.102REF.		
D	0.550	0.600	0.670
E	0.250	0.300	0.370
b	0.160	0.190	0.230
L	0.215	0.245	0.275
e	0.360 BSC		

Recommended PCB Layout (Unit: mm)

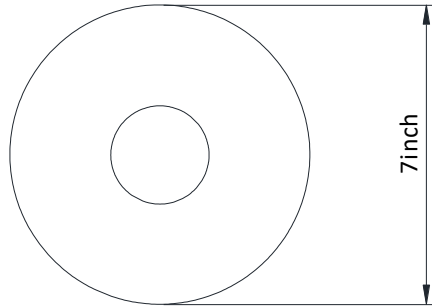


Notes:

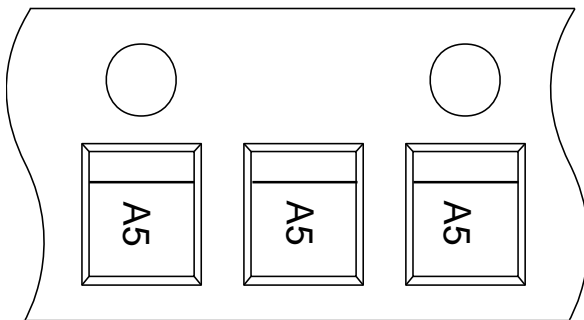
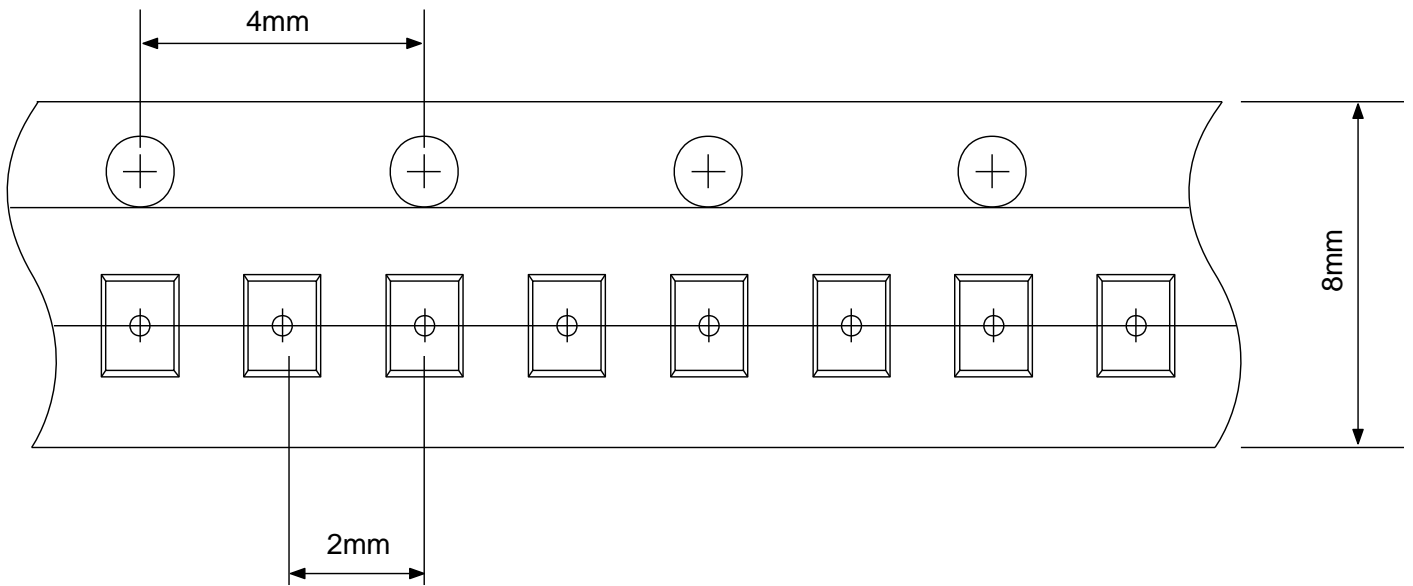
This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

TAPE AND REEL INFORMATION

Reel Dimensions



Tape Dimensions




User Direction of Feed

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